

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 278285US0PCT		SERIAL NO. 10/549,364	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Makoto ISHIDA, et al.			
				FILING DATE July 17, 2006		GROUP 2826	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
	AO						
	AP						
	AO						
	AR						
	AS						
	AT						
	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
	AW	D. AKAI ET AL, Science d Direct, "Epitaxial Growth of Pt(001) thin films on Si substrates using an epitaxial γ -Al ₂ O ₃ (001) buffer layer, Journal of Crystal Growth 264 (2004) 463-467					
	AX	D. AKAI, APPLIED PHYSICS LETTERS 86, 202906 (2005), Ferroelectric properties of sol-gel delivered epitaxial Pb(Zr _x , Ti _{1-x})O ₃ THIN FILMS ON SI USING EPITAXIAL γ -Al ₂ O ₃ Layers					
	AY						
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner					Date Considered		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							